KD*P Pockels Cell

9mm aperture, 200nm to 1600nm

DATASHEET



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Features

- High Extinction Ratio
- Low Insertion Loss
- High Damage Threshold
- Low Capacitance
- Low Current Leakage
- Low Cost

Applications

- Industrial Laser System
- Medical Laser System
- Aesthetic Laser System
- Military Laser System

KD*P (Potassium Dideuterium Phosphate) is the most widely used material for electro-optical applications due to its excellent E-O properties. An electro-optic material such as KD*P can alter the polarization state of light passing through it, when an applied voltage induces birefringence change in the crystal.

For amplitude modulation, polarized light is essential because the modulation process relies on controlling the intensity of light based on its polarization state. By incorporating input and output polarizers, the extinction ratio (ER) of the device is significantly improved.

Specifications

Parameter	Min	Typical	Мах	Unit
Chemical Formula				
Transparency Range	200		1600	nm
Insertion Loss		< 2		%
Collimation		< 0.5		۰
Wave front distortion (@633nm)		λ/6		
Clear Aperture		Ø9		mm
Coatings	AR@1064nm(R<0.2%)			
Nonlinear Coefficients (d36)		0.40		pm/V
Refractive Index (1064nm)	No=1.4948, Ne=1.4554			
E-O Coefficients	r41=8.8pm/V, r63=25pm/V			
Longitudinal Half-wave Voltage	Vn=2.98KV (546nm)			
Quarter-wave voltage		~ 3400		V
Absorptance		0.006		1/cm
Optical Damage Threshold	> 1GW/ cm ² 10ns 10Hz at 1064nm			
Extinction Ratio		> 30		dB
Size		Ø 25.4x39		mm
Voltage Extinction Ratio	>2000:1 (CP) >1500:1 (PP)			
Capacitance		< 6		рF
Scratch/Dig				

* Sellmeier equations of KD*P:(λ in um):

no2=1.9575544+0.2901391\2/(\2-0.0281399)-0.02824391\2+0.004977826\2 ne2=1.5005779+0.6276034\2/(\2-0.0131558)-0.01054063\2+0.002243821\2

Note: The specifications provided are for general applications with a cost-effective approach. If you need to narrow or expand the tolerance, coverage, limit, or qualifications, please [click this <u>link</u>]:

Warning: Do not use it, if you are not well trained. Do not clean the optical surfaces. Dot not solder on crystals causing cracks. High voltage on the electrodes is extremely dangerous.

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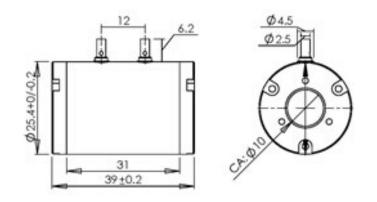
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Mechanical Dimensions (mm)



*Product dimensions may change without notice. This is sometimes required for non-standard specifications.

Ordering Information

	1		1	1	1	1
Prefix	Туре	Wavelength	Aperture			
PCDK-		430~700 nm = 0550 700~1000 nm = 0850 1064 nm = 1064			9mm = 1	

E sales@photonwares.com